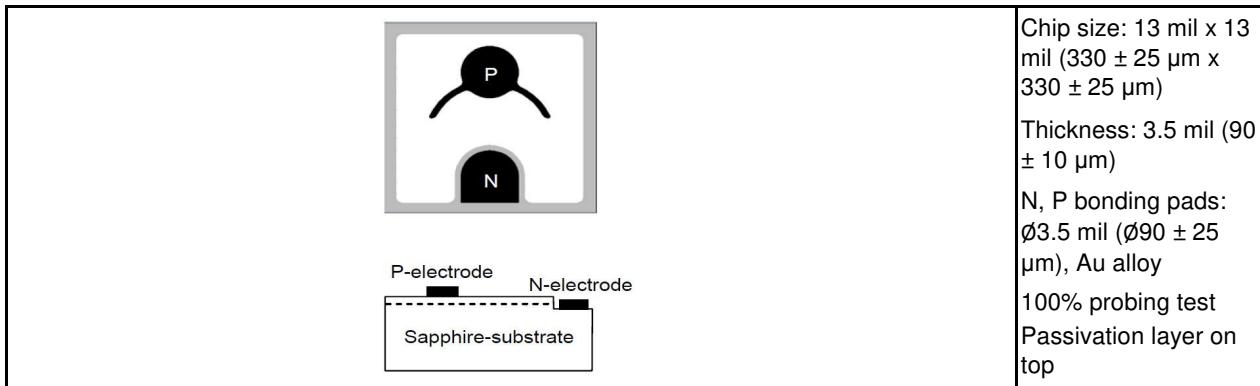



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**LED Chip blue**
**EOLC-460-34**

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Radiation	Type	Electrodes
Blue	InGaN / sapphire	N+P-up


**Absolute Maximum Ratings**
 $T_{\text{amb}} = 25^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Rating	Unit
Forward DC current	$I_F$	30	mA
Reverse voltage	$I_R$	5	V
Junction temperature	$T_J$	115	°C
Storage temperature chip	$T_{\text{STG}}$	-40...+85	°C
Storage temperature chip on tape	$T_{\text{STG}}$	+0...+40	°C
Transport. temperature chip on tape	$T_{\text{STG}}$	-20...+65	°C
Soldering temperature	$T_{\text{SOL}}$	+280 (10 sec)	°C

**Optical and Electrical Characteristics**
 $T_{\text{amb}} = 25^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Cond.	Min	Typ	Max	Unit
Forward voltage	$V_F$	$I_F=10 \mu\text{A}$	2.0			V
Forward voltage	$V_F$	$I_F=20 \text{ mA}$	2.8		3.6	V
Reverse current	$I_R$	$V_R=5 \text{ V}$			2	$\mu\text{A}$
Radiant flux	$I_V$	$I_F=20 \text{ mA}$	125	150		mcd
Dominant wavelength	$\lambda_D$	$I_F=20 \text{ mA}$	455	460	465	nm
FWHM	$\Delta\lambda$	$I_F=20 \text{ mA}$		25		nm

\*Measured on gold plate without an encapsulant

**Packing**

Dice on adhesive film with wire-bond on top



We reserve the right to make changes to improve technical design and may do so without further notice. Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer.



## Data Sheet

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Fig.1-Relative Luminous Intensity vs. Forward Current

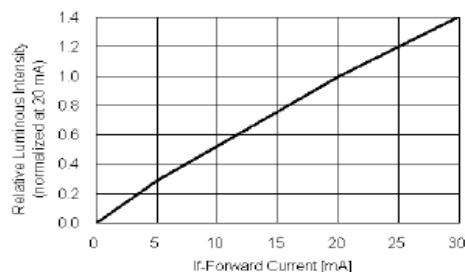


Fig.2- Forward Current vs. Forward Voltage

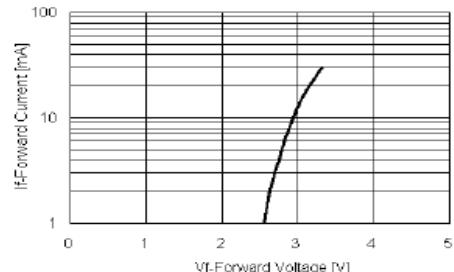


Fig.3-Relative Intensity (@20mA) vs. Ambient Temperature

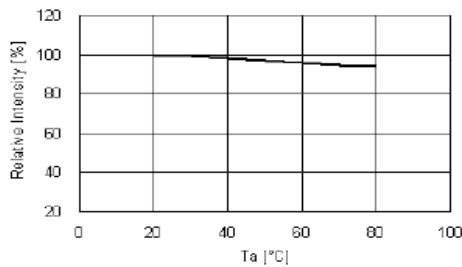


Fig.4-Forward Voltage (@20mA) vs. Ambient Temperature

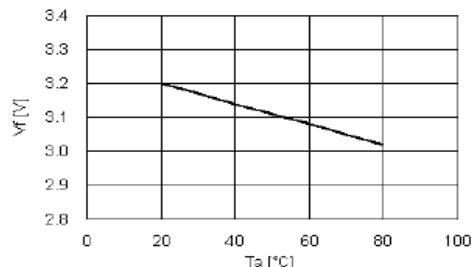


Fig.5-Dominant Wavelength(@20mA) vs. Ambient Temperature

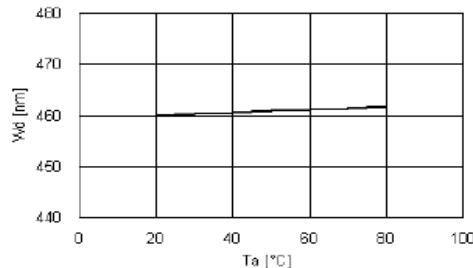


Fig.6 Maximum Driving Forward DC Current vs. Ambient Temperature (Derating based on Tj max. = 115°C)

